

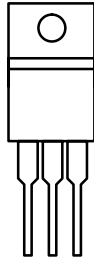


P-Channel 55-V (D-S), 175°C MOSFET

PRODUCT SUMMARY

$V_{(BR)DSS}$ (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-55	0.008	-75 ^a

TO-220AB



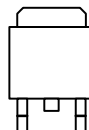
G D S

Top View

SUP75P05-08

DRAIN connected to TAB

TO-263

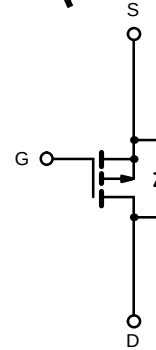


G D S

Top View

SUB75P05-08

175°C Rated
Maximum Junction Temperature
TrenchFET®
Power MOSFETs



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	-55	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ($T_J = 175^\circ\text{C}$)	$T_C = 25^\circ\text{C}$	I_D	-75 ^a	A
	$T_C = 150^\circ\text{C}$		-47	
Pulsed Drain Current		I_{DM}	-240	
Avalanche Current		I_{AR}	-75	
Repetitive Avalanche Energy ^b		E_{AR}	280	mJ
Power Dissipation	$T_C = 25^\circ\text{C}$ (TO-220AB and TO-263)		250 ^d	
	$T_A = 125^\circ\text{C}$ (TO-263) ^c		3.7	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 175	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Limit	Unit
Junction-to-Ambient	PCB Mount (TO-263) ^c	R_{thJA}	40	$^\circ\text{C/W}$
	Free Air (TO-220AB)	R_{thJA}	62.5	
Junction-to-Case		R_{thJC}	0.6	

Notes:

- Package limited.
- Duty cycle $\leq 1\%$.
- When mounted on 1" square PCB (FR-4 material).
- See SOA curve for voltage derating.

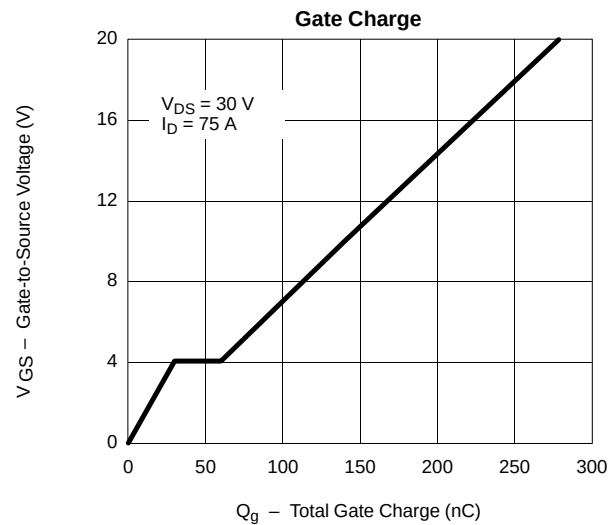
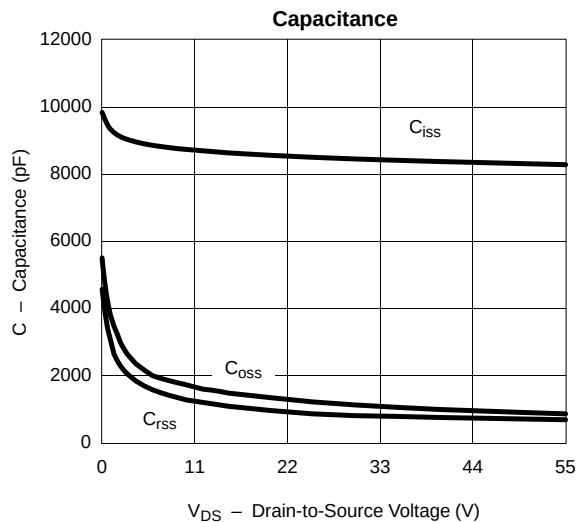
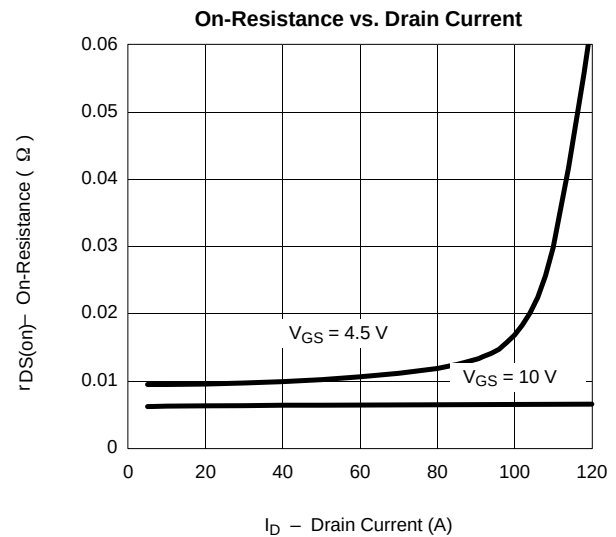
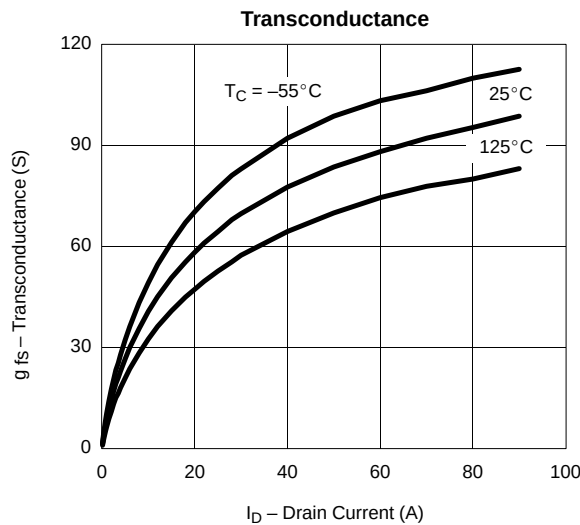
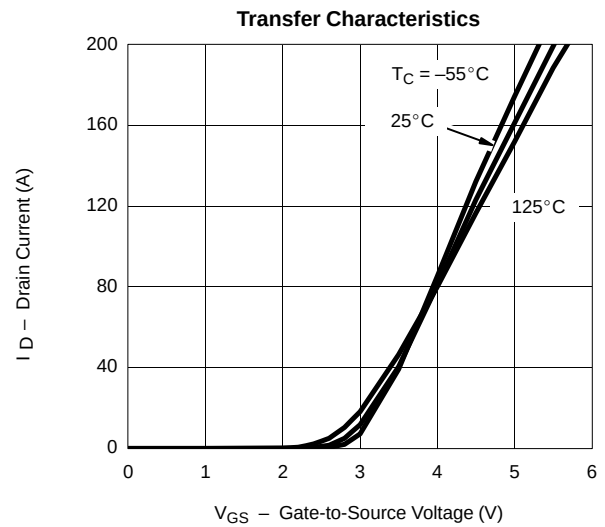
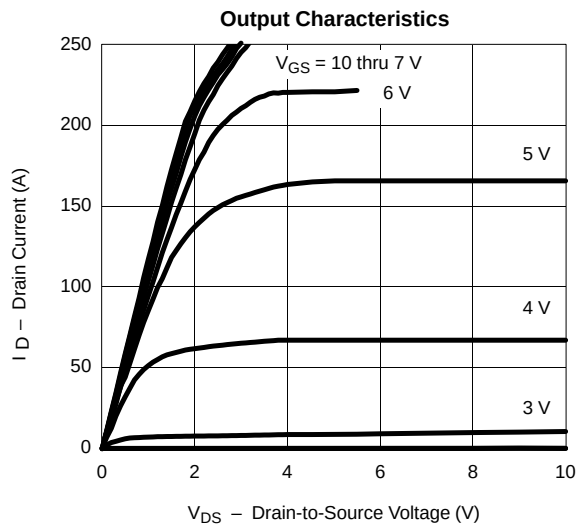
For SPICE model information via the Worldwide Web: <http://www.vishay.com/www/product/spice.htm>

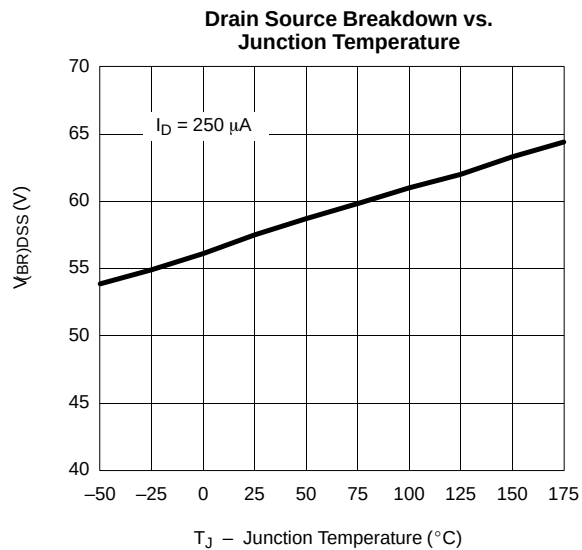
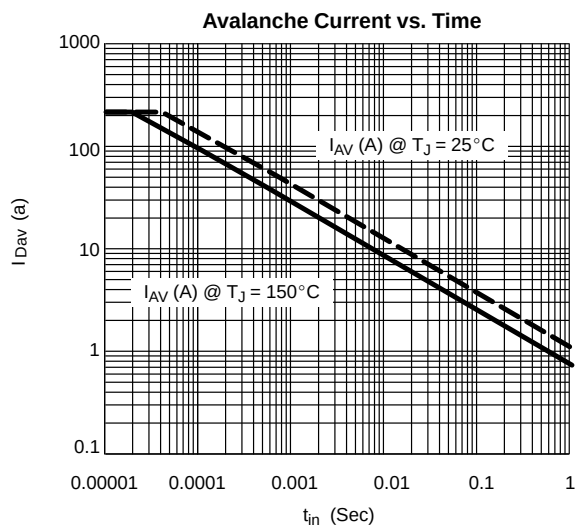
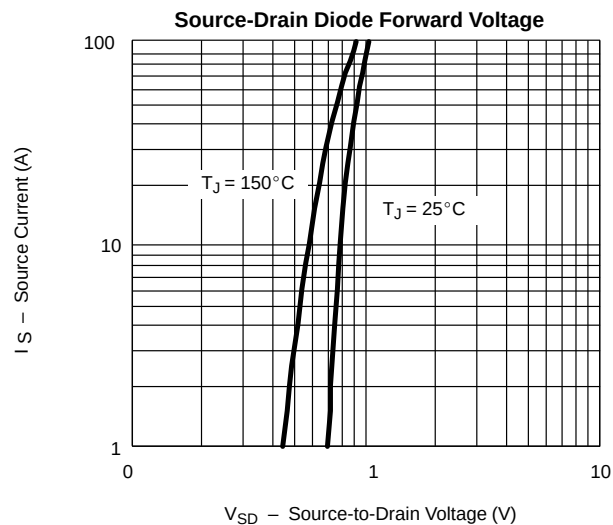
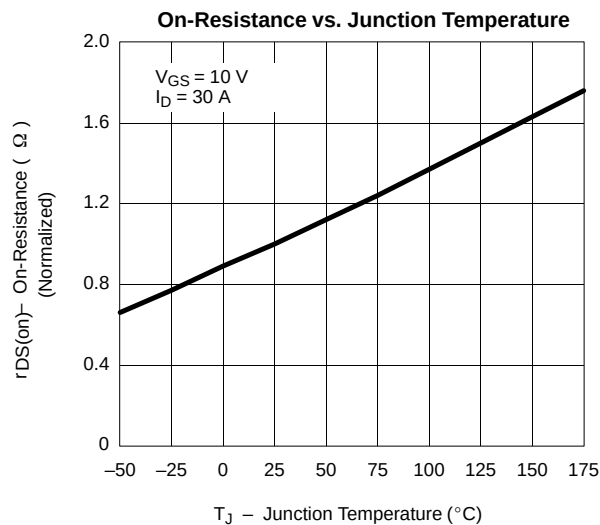


SPECIFICATIONS (T _J = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = −250 μA	−55			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = −250 μA	−1	−2	−3	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = −44 V, V _{GS} = 0 V			−1	μA
		V _{DS} = −44 V, V _{GS} = 0 V, T _J = 125 °C			−50	
		V _{DS} = −44 V, V _{GS} = 0 V, T _J = 175 °C			−700	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = −5 V, V _{GS} = −10 V	−120			A
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = −10 V, I _D = −30 A			0.008	Ω
		V _{GS} = −4.5 V, I _D = −20 A			0.013	
		V _{GS} = −10 V, I _D = −30 A, T _J = 125 °C			0.014	
		V _{GS} = −10 V, I _D = −30 A, T _J = 175 °C			0.016	
Forward Transconductance ^a	g _{fs}	V _{DS} = −15 V, I _D = −30 A		75		S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = −25 V, f = 1 MHz		8500		pF
Output Capacitance	C _{oss}			1220		
Reverse Transfer Capacitance	C _{rss}			915		
Total Gate Charge ^c	Q _g	V _{DS} = −30 V, V _{GS} = −10 V, I _D = −75 A		140	225	nC
Gate-Source Charge ^c	Q _{gs}			30		
Gate-Drain Charge ^c	Q _{gd}			30		
Turn-On Delay Time ^c	t _{d(on)}	V _{DD} = −30 V, R _L = 0.47 Ω I _D ≈ −75 A, V _{GEN} = −10 V, R _G = 2.5 Ω		13	20	ns
Rise Time ^c	t _r			140	225	
Turn-Off Delay Time ^c	t _{d(off)}			115	185	
Fall Time ^c	t _f			175	300	
Source-Drain Diode Ratings and Characteristics (T _C = 25 °C) ^b						
Continuous Current	I _S				−75	A
Pulsed Current	I _{SM}				−240	
Forward Voltage ^a	V _{SD}	I _F = −75 A, V _{GS} = 0 V		−1.1	−1.3	V
Reverse Recovery Time	t _{rr}	I _F = −75 A, di/dt = 100 A/μs		60	120	ns
Peak Reverse Recovery Current	I _{RM(REC)}			2.2	3.5	A
Reverse Recovery Charge	Q _{rr}				0.176	0.21

Notes:

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

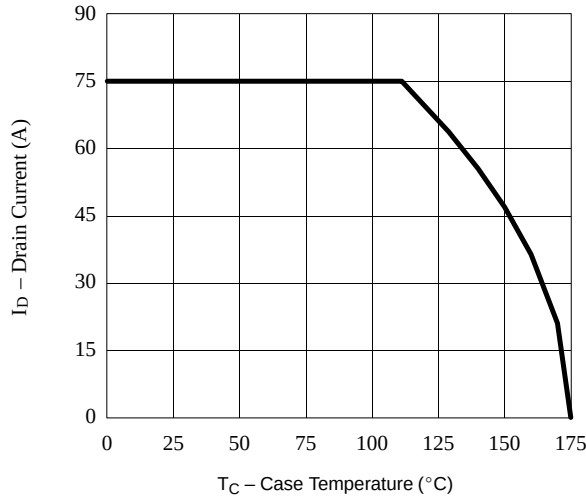
**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**

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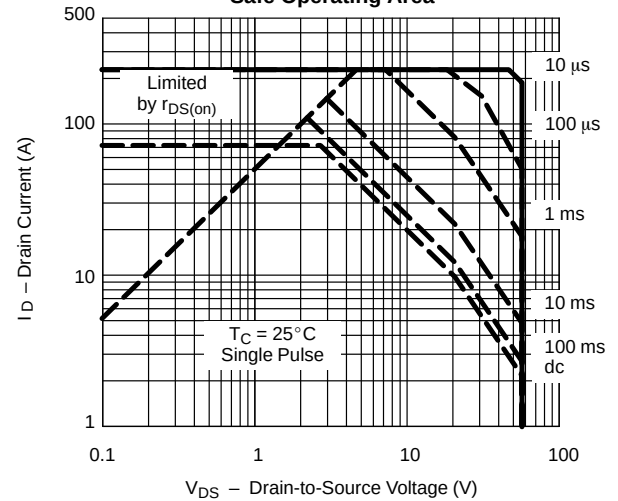


THERMAL RATINGS

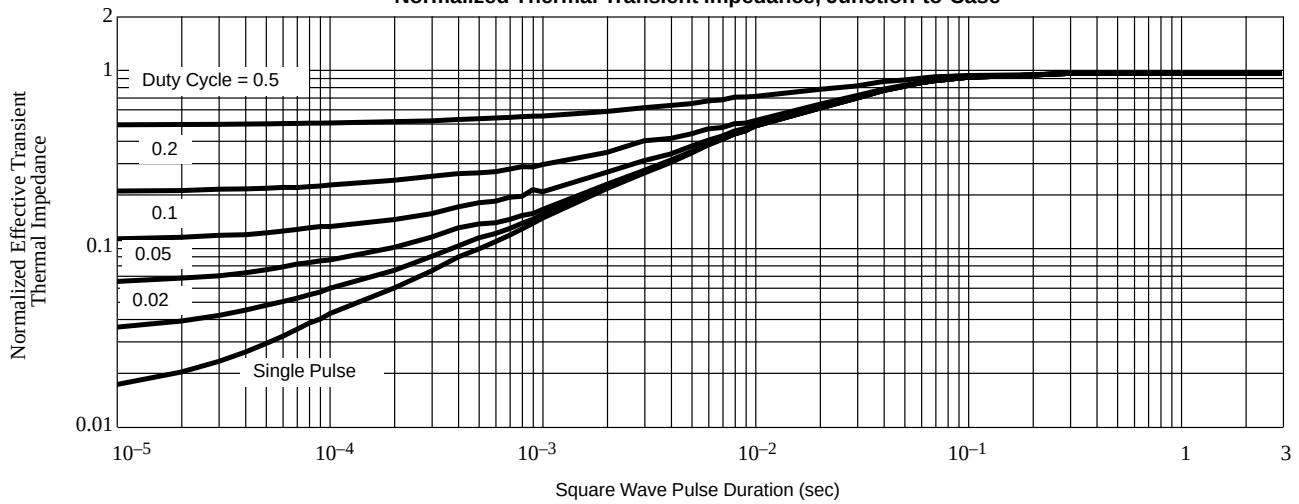
**Maximum Avalanche and Drain Current
vs. Case Temperature**



Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case





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